

# RJP4006AGE

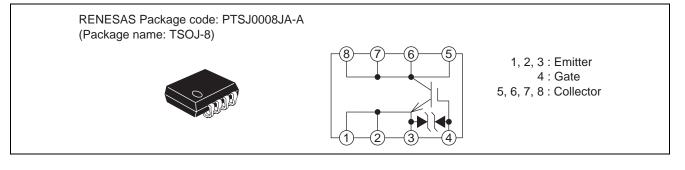
Nch IGBT for Strobe Flash

REJ03G1865-0100 Rev.1.00 Dec 09, 2009

#### Features

- Ultra small surface mount package
- V<sub>CES</sub>: 400 V
- I<sub>CM</sub>: 120 A
- Drive voltage: 2.7 V
- Pb-free
- Halogen-free

#### Outline



### Applications

Strobe flash for cameras

### **Maximum Ratings**

 $(Tc = 25^{\circ}C)$ 

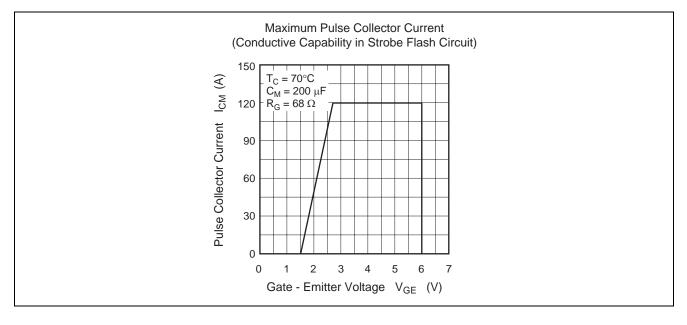
Parameter	Symbol	Ratings	Unit	Conditions
Collector-emitter voltage	V <sub>CES</sub>	400	V	$V_{GE} = 0 V$
Gate-emitter voltage	V <sub>GES</sub>	±6	V	$V_{CE} = 0 V$
Collector current (Pulse)	I <sub>CM</sub>	120	A	C <sub>M</sub> = 200 μF (see performance curve)
Junction temperature	Tj	-40 to +150	С°	
Storage temperature	Tstg	-40 to +150	°C	

## **Electrical Characteristics**

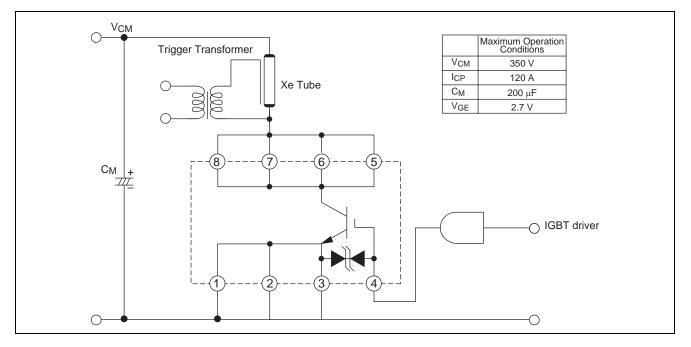
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						$(Tj = 25^{\circ}C)$
Parameter	Symbol	Min.	Тур.	Max.	Unit	Test conditions
Collector-emitter leakage current	I <sub>CES</sub>	—	—	1	μΑ	$V_{CE} = 400 \text{ V}, \text{ V}_{GE} = 0 \text{ V}$
Gate-emitter leakage current	I <sub>GES</sub>	—	—	±10	μΑ	$V_{GE} = \pm 6 \text{ V},  V_{CS} = 0 \text{ V}$
Gate-emitter threshold voltage	$V_{\text{GE(th)}}$	0.4	0.6	1.2	V	$V_{CE} = 10 \text{ V}, I_{C} = 1 \text{ mA}$
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	—	4.5	9.0	V	$I_{C} = 120 \text{ A}, V_{GE} = 2.7 \text{ V}$
Input capacitance	Cies	—	4200		рF	$V_{CE} = 25 \text{ V}, \text{ V}_{GE} = 10 \text{ V},$
						f = 1 MHz

### **Performance Curves**



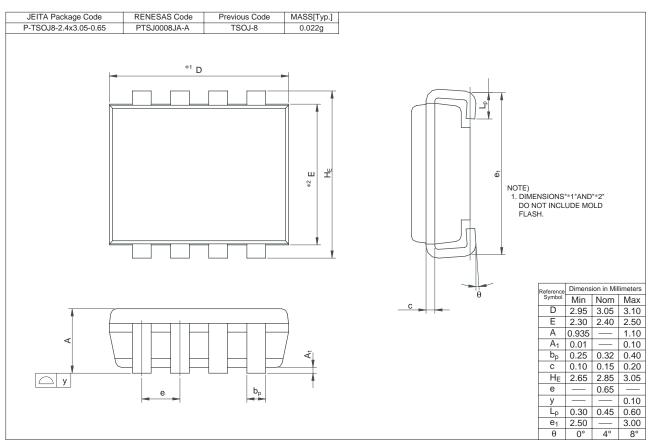
### **Application Example**



### **Precautions on Usage**

- 1. IGBT has MOS structure and its gate is insulated by thin silicon oxide. So please handle carefully to protect the device from electrostatic charge.
- 2. Gate drive voltage during on-period must be applied to satisfy the rating of maximum pulse collector current. And turn-off dv/dt must become less than 400 V/  $\mu$ s. In general, when R<sub>G (off)</sub> = 68  $\Omega$ , it is satisfied.
- 3. The operation life should be endured until repeated discharge of 5,000 times under the charge current ( $I_{Xe} \le 120 \text{ A}$  : full luminescence condition) of main capacitor. Repetition period under full luminescence condition is over 3 seconds.

# **Package Dimensions**



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### **Order Code**

Lead form	Standard packing	Quantity	Standard order code	Standard order code example
Surface-mounted type	Taping	3000	Type name – 00 – P5	RJP4006AGE-00-P5

Note : Please confirm the specification about the shipping in detail.

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